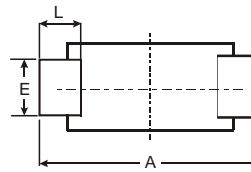
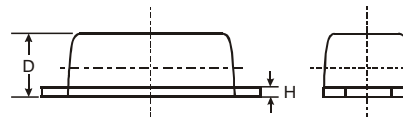
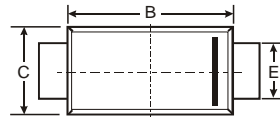
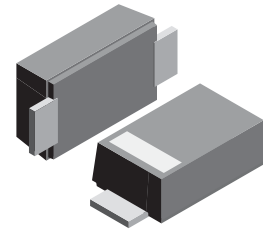


**VOLTAGE RANGE: 50 - 1000V**  
**CURRENT: 2.0 A**

### Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop, High Efficiency
- Low Power Loss
- Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-0



SMAF			
Dim	Min	Max	Typ
A	4.75	4.85	4.80
B	3.68	3.72	3.70
C	2.57	2.63	2.60
D	0.097	1.03	1.00
E	1.38	1.42	1.40
H	0.13	0.17	0.15
L	0.63	0.67	0.65
All Dimensions in mm			

### Mechanical Data

- Case: SMAF, Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.0018 ounce, 0.064 grams



### Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	RS2AAF	RS2BAF	RS2DAF	RS2GAF	RS2JAF	RS2KAF	RS2MAF	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current @ T <sub>L</sub> = 90°C	I <sub>O</sub>	2.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	50							A
Forward Voltage @ I <sub>F</sub> = 2.0A	V <sub>FM</sub>	1.30							V
Peak Reverse Current @ T <sub>A</sub> = 25°C At Rated DC Blocking Voltage @ T <sub>A</sub> = 125°C	I <sub>RM</sub>	5.0 300							μA
Reverse Recovery Time (Note 1)	t <sub>rr</sub>	150				250	500		nS
Typical Junction Capacitance (Note 2)	C <sub>j</sub>	50							pF
Typical Thermal Resistance (Note 3)	R <sub>θJL</sub>	20							°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-50 to +150							°C

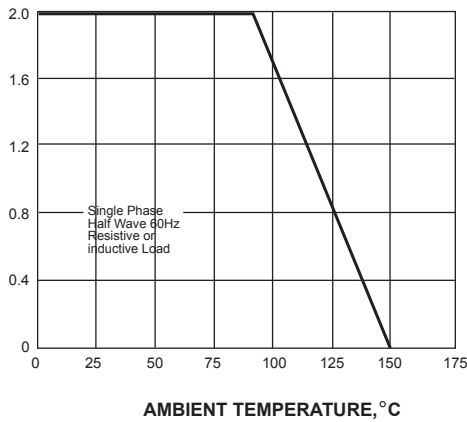
Note: 1. Measured with I<sub>F</sub> = 0.5A, I<sub>R</sub> = 1.0A, I<sub>rr</sub> = 0.25A. See figure 5.  
 2. Measured at 1.0 MHz and applied reverse voltage of 4.0 V DC.  
 3. Mounted on P.C. Board with 8.0mm<sup>2</sup> land area.



## RATINGS AND CHARACTERISTIC CURVES RS2AAF THRU RS2MAF

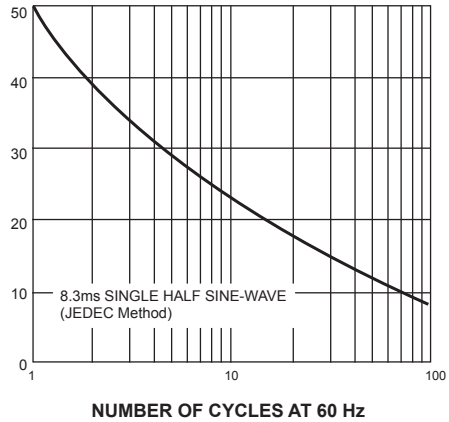
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



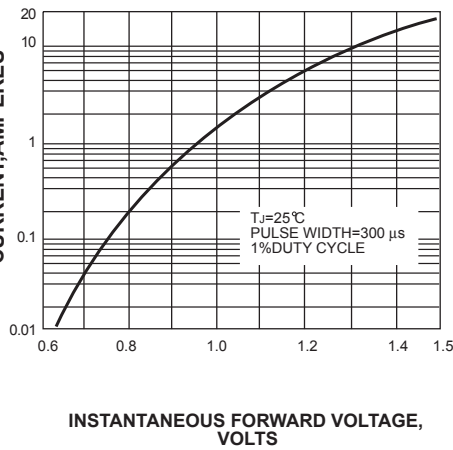
PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



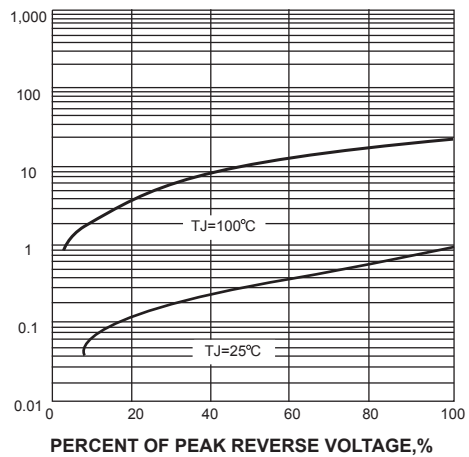
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



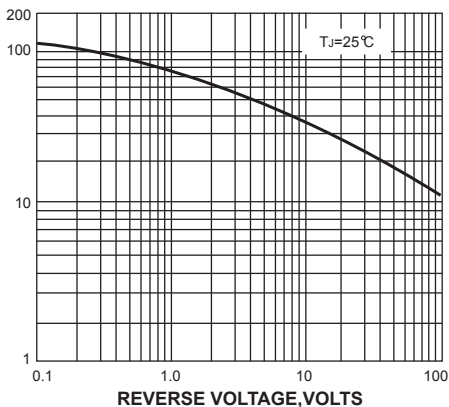
INSTANTANEOUS REVERSE CURRENT, MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

